

MTMC8E2A0LBF

Dual N-channel MOSFET

For lithium-ion secondary battery protection circuit

■ Features

- Low drain-source ON resistance: $R_{DS(on)typ.} = 15\text{ m}\Omega$ ($V_{GS} = 4.5\text{ V}$)
- Built-in gate resistor
- Halogen-free / RoHS compliant
(EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: 4B

■ Packaging

MTMC8E2A0LBF Embossed type (Thermo-compression sealing):
3 000 pcs / reel (standard)

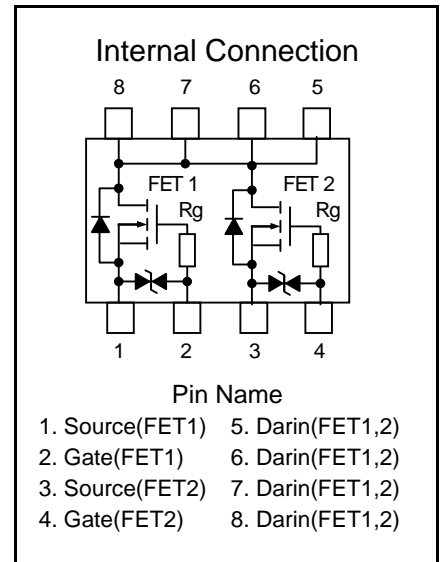
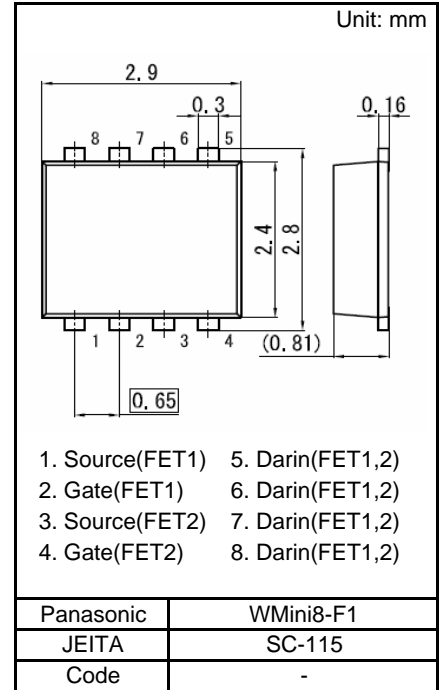
■ Absolute Maximum Ratings $T_a = 25\text{ }^\circ\text{C}$

Parameter		Symbol	Rating	Unit
FET1	Drain-source Voltage	V_{DS}	20	V
	Gate-source Voltage	V_{GS}	± 12	V
FET2	Drain Current	I_D	7.0	A
	Peak Drain Current	I_{Dp}	42	A
Overall	Total Power Dissipation	$PD1^{*1}$	1.0	W
		$PD2^{*1,*2}$	1.2	
		$PD3^{*3}$	0.4	
	Channel Temperature Range	T_{ch}	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 to +150	$^\circ\text{C}$	

Note: *1 Glass epoxy board: $25.4\text{ mm} \times 25.4\text{ mm} \times 0.8\text{ mm}$ Copper foil of the drain portion should have a area of 300 mm^2 or more
PD absolute maximum rating Non-heat sink: 400 mW

*2 $t = 10\text{ s}$

*3 Non-heat sink



Resistance Value	R_g	1	$k\Omega$
------------------	-------	---	-----------

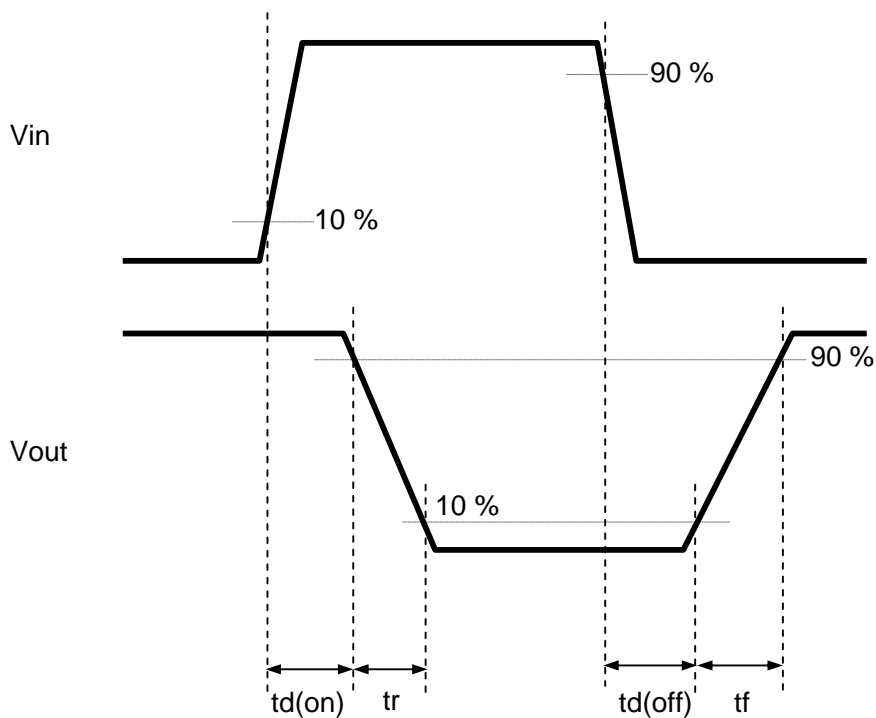
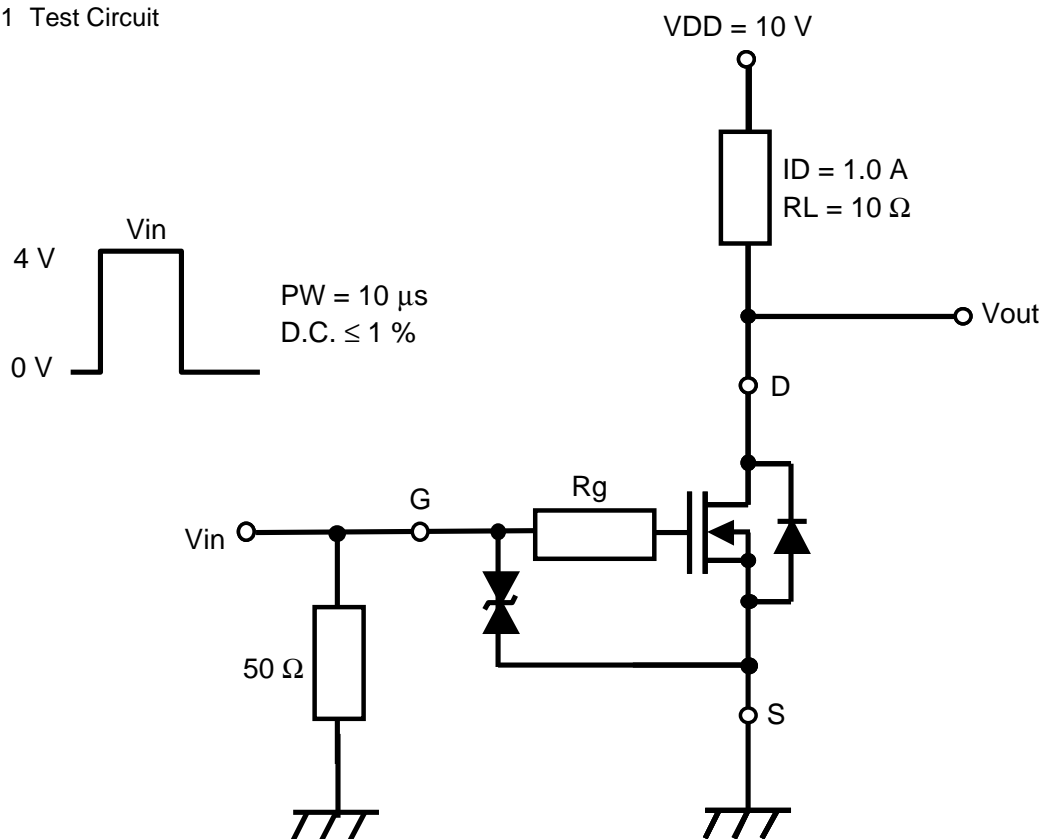
■ Electrical Characteristics Ta = 25 °C ± 3 °C
FET1,FET2

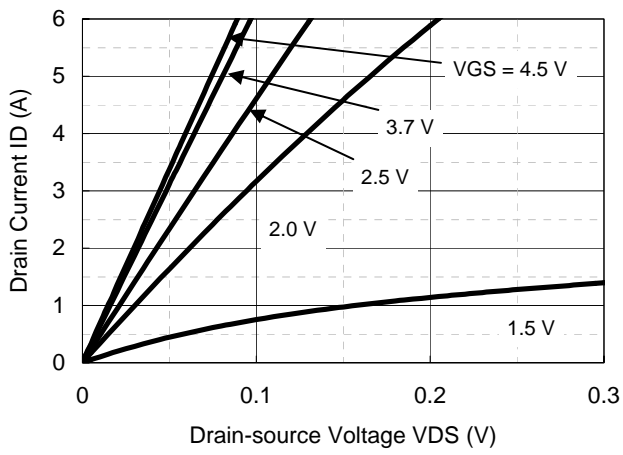
Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Drain-source Breakdown Voltage	VDSS	ID = 1.0 mA, VGS = 0 V	20			V
Zero Gate Voltage Drain Current	IDSS	VDS = 20 V, VGS = 0 V			1.0	μA
Gate-source Leakage Current	IGSS	VGS = ±8.0 V, VDS = 0 V			±10	μA
Gate-source Threshold Voltage	Vth	ID = 1.0 mA, VDS = 10 V	0.40	0.85	1.30	V
Drain-source On-state Resistance	RDS(on)1	ID = 2.0 A, VGS = 4.5 V		15	21	mΩ
	RDS(on)2	ID = 2.0 A, VGS = 3.7 V		18	25	
	RDS(on)3	ID = 2.0 A, VGS = 2.5 V		22	33	
Forward transfer admittance	Yfs	ID = 1.0 A, VDS = -10 V	3.0			S
Input Capacitance	Ciss	VDS = 10 V, VGS = 0 V, f = 1 MHz		1 450		pF
Output Capacitance	Coss			100		
Reverse Transfer Capacitance	Crss			90		
Turn-on Delay Time *1	td(on)	VDD = 10 V, VGS = 0 to 4 V, ID = 1.0 A		0.33		μs
Rise Time *1	tr			0.70		
Turn-off Delay Time *1	td(off)	VDD = 10 V, VGS = 4 to 0 V, ID = 1.0 A		4.0		μs
Fall Time *1	tf			2.0		

Note: Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

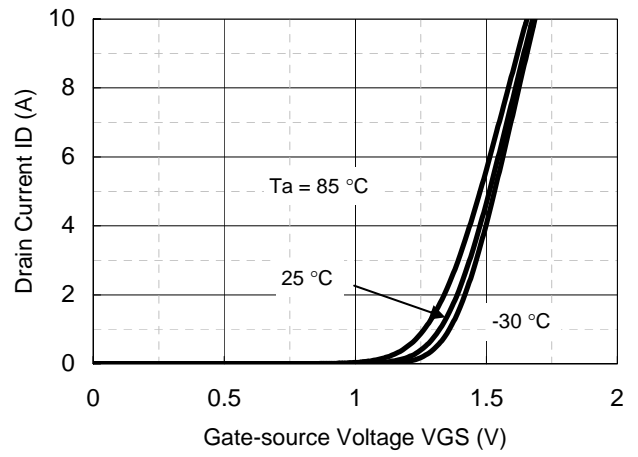
*1 See Test Circuit.

*1 Test Circuit

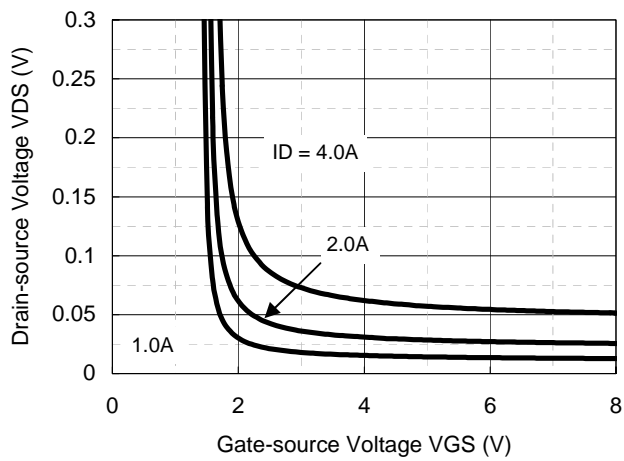




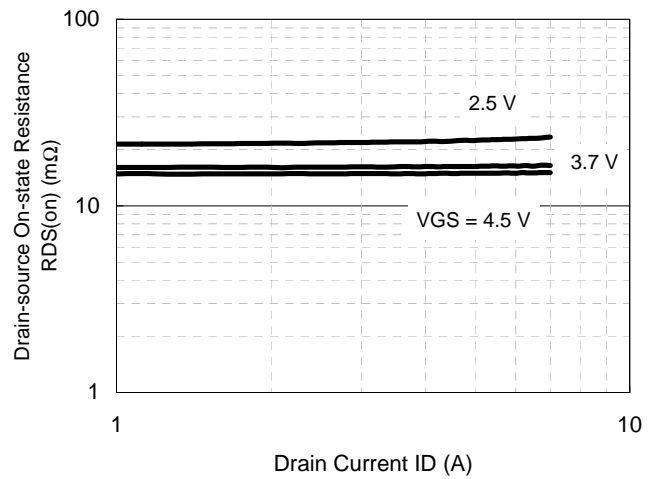
ID - VDS



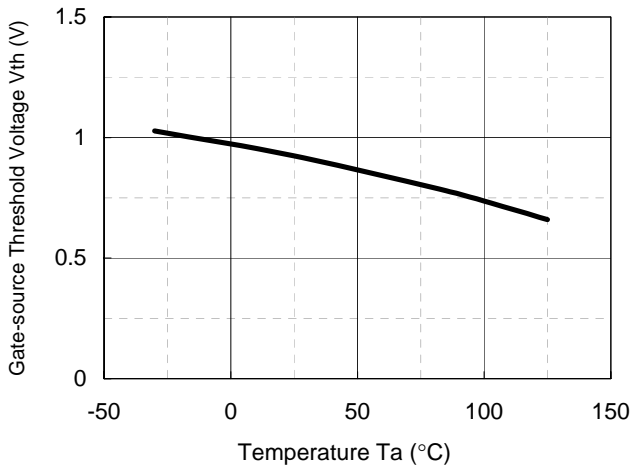
ID - VGS



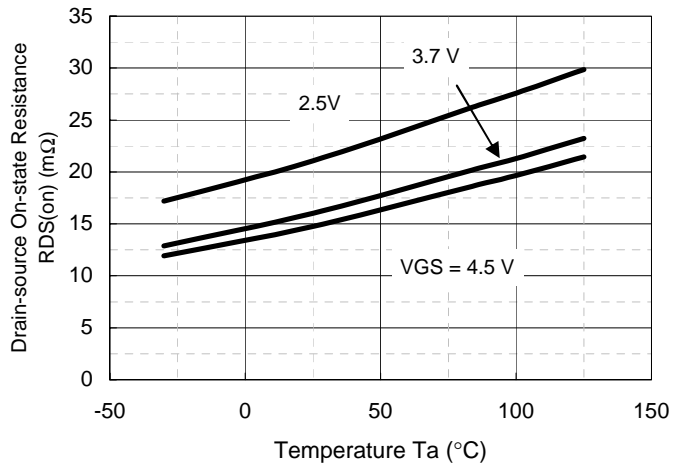
VDS - VGS



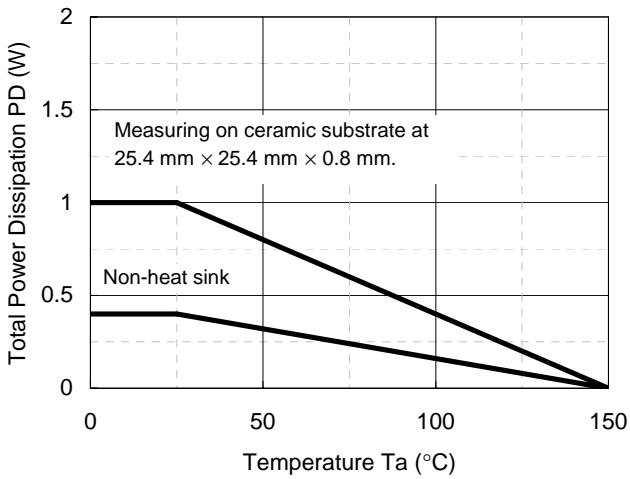
RDS(on) - ID



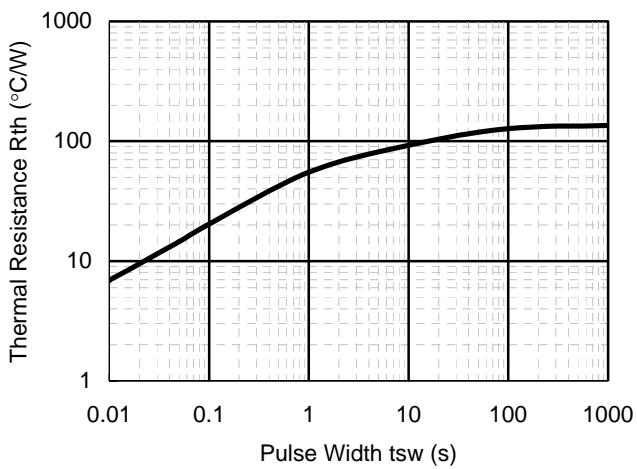
V_{th} - T_a



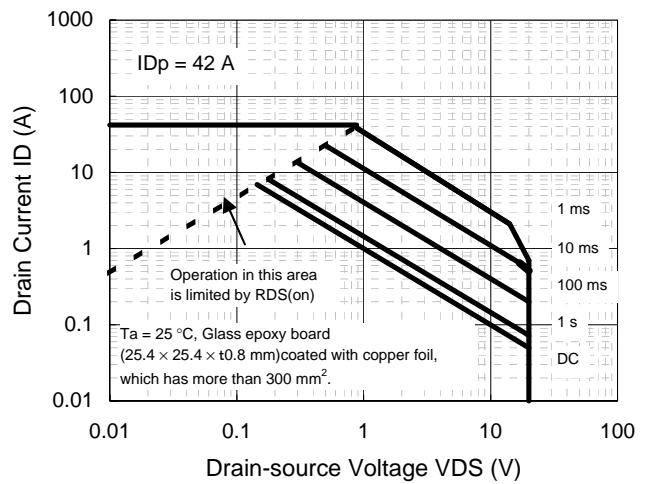
$R_{DS(on)}$ - T_a



P_D - T_a



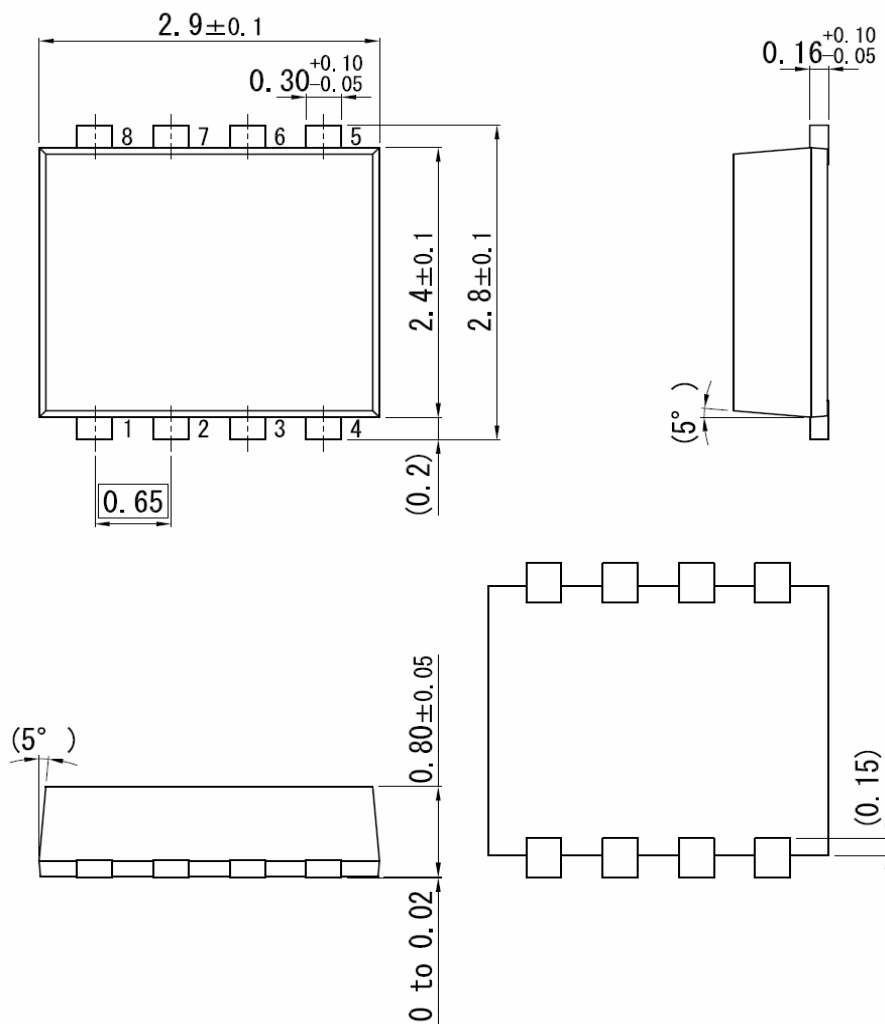
R_{th} - t_{sw}



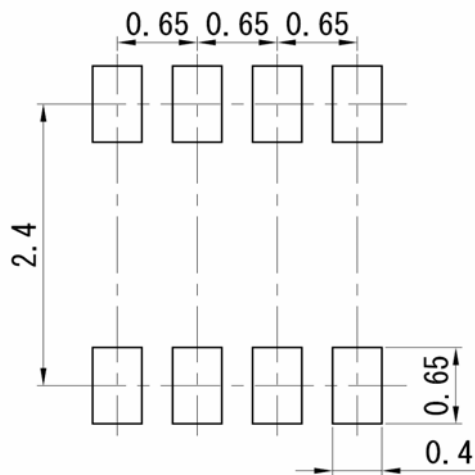
Safe Operating Area

WMini8-F1

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



Request for your special attention and precautions in using the technical information and semiconductors described in this book

- (1) If any of the products or technical information described in this book is to be exported or provided to non-residents, the laws and regulations of the exporting country, especially, those with regard to security export control, must be observed.
- (2) The technical information described in this book is intended only to show the main characteristics and application circuit examples of the products. No license is granted in and to any intellectual property right or other right owned by Panasonic Corporation or any other company. Therefore, no responsibility is assumed by our company as to the infringement upon any such right owned by any other company which may arise as a result of the use of technical information described in this book.
- (3) The products described in this book are intended to be used for general applications (such as office equipment, communications equipment, measuring instruments and household appliances), or for specific applications as expressly stated in this book.
Consult our sales staff in advance for information on the following applications:
 - Special applications (such as for airplanes, aerospace, automotive equipment, traffic signaling equipment, combustion equipment, life support systems and safety devices) in which exceptional quality and reliability are required, or if the failure or malfunction of the products may directly jeopardize life or harm the human body.It is to be understood that our company shall not be held responsible for any damage incurred as a result of or in connection with your using the products described in this book for any special application, unless our company agrees to your using the products in this book for any special application.
- (4) The products and product specifications described in this book are subject to change without notice for modification and/or improvement. At the final stage of your design, purchasing, or use of the products, therefore, ask for the most up-to-date Product Standards in advance to make sure that the latest specifications satisfy your requirements.
- (5) When designing your equipment, comply with the range of absolute maximum rating and the guaranteed operating conditions (operating power supply voltage and operating environment etc.). Especially, please be careful not to exceed the range of absolute maximum rating on the transient state, such as power-on, power-off and mode-switching. Otherwise, we will not be liable for any defect which may arise later in your equipment.
Even when the products are used within the guaranteed values, take into the consideration of incidence of break down and failure mode, possible to occur to semiconductor products. Measures on the systems such as redundant design, arresting the spread of fire or preventing glitch are recommended in order to prevent physical injury, fire, social damages, for example, by using the products.
- (6) Comply with the instructions for use in order to prevent breakdown and characteristics change due to external factors (ESD, EOS, thermal stress and mechanical stress) at the time of handling, mounting or at customer's process. When using products for which damp-proof packing is required, satisfy the conditions, such as shelf life and the elapsed time since first opening the packages.
- (7) This book may be not reprinted or reproduced whether wholly or partially, without the prior written permission of our company.



Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литера Н,
помещение 100-Н Офис 331